

HAL501U Hall-effect switch integrated circuits for high temperature operating based on Hall-effect principle, apply the semiconductor monolithic technology, which includes a voltage regulator, Hall voltage generator, differential amplifier, Schmitt trigger and an open-collector output on a single silicon chip. ICs can convert the input magnetic field signal into digital voltage output.

Small size

High Sensitivity

Quick Response

Good Temperature Performance

**High Accuracy** 

Excellent Reliability

Non-contact Switch

Automotive Ignition

Position control

**Revolution detection** 

Safe alarm device

Textile control system





○ 3, V<sub>out</sub>

2, GND

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	T LO III	Symb	Value			Unit
Parameter	lest Condition	ol	Min	Тур	Max	
Supply Voltage	Vcc=4.5V 24V	Vcc	3.8	-	30	V
Output Low Voltage	Vcc=4.5v, Vo=24V Io=20mA, B ≥ BOP	VOL	-	175	400	mV
Output Leakage Current	Vo=24V, B <brp< td=""><td>IOH</td><td>-</td><td>&lt;1.0</td><td>10</td><td>μA</td></brp<>	IOH	-	<1.0	10	μA
Supply Current	Vcc=24V Vo open-collector output	lcc	-	6	10	mA
Output Rise time	Vcc=12V	tr	-	0.2	1.5	μS
Output Fall time	R L =820 Ω C <sub>L</sub> =20pF	tf	-	0.18	1.5	μS
Frequency		F		100		KHz

T<sub>A</sub>=25

## (Unit: mT)

Deremeter	aymbol					
Farameter	Symbol	Min	Тур	Max	Unit	
Operate Point	B <sub>OP</sub>	6	12	16	mT	
Release Point	B <sub>RP</sub>	2	7	11	mT	
Hysteresis	B <sub>hys</sub>		5		mT	

Model	HAL501U	Operating Temperature	-40	150	Package	TO-92S	1000pcs/bag
						SOT-23-3	3000pcs/reel

DC Operating Parameters  $T_{\rm A}$  = -40 C to 150 C,  $V_{\rm DD}$  = 2.5V to 24V (unless otherwise specified)

South pole (TO)	B> B <sub>OP</sub>	High
North pole (SOT)	B> B <sub>OP</sub>	High
Null or weak magnetic field	B= 0 or B < BRP	Low





1.VCC 2.Ground 3.Output

- Mechanical Stress Should be lessened as far as possible in the process of assembly, and add one 1K pull-up Resistor between Pin1 and Pin 3.
- The soldering temperature at the leads should be less than 260 with 5 seconds.